# HD74HC279

Quad.  $\overline{S}$ - $\overline{R}$  Latches

# HITACHI

#### Description

The latch is ideally suited for use as temporary stage for binary information processing and input/output units. When either  $\overline{S}$  or  $\overline{R}$  is low, output is dependent on  $\overline{R}$  input. When both inputs are high, Output is stored before the indicated steady-state input conditions were established. And when both inputs are low, output is high, but this high level are uncontinuance, if either of input goes high.

#### Features

- High Speed Operation:  $t_{pd}$  ( $\overline{S}$  to Q) = 10 ns typ ( $C_L = 50 \text{ pF}$ )
- High Output Current: Fanout of 10 LSTTL Loads
- Wide Operating Voltage:  $V_{CC} = 2 \text{ to } 6 \text{ V}$
- Low Input Current: 1 µA max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 2  $\mu$ A max (Ta = 25°C)

#### **Function Table**

Input		Output
<b>S</b> <sup>∗2</sup>	R	Q
Н	Н	Q <sub>0</sub>
L	н	Н
Н	L	L
L	L	H*1

H: High level

L : Low level

Q<sub>0</sub>: The level of Q respectively, before the indicated steady-state input conditions were established.

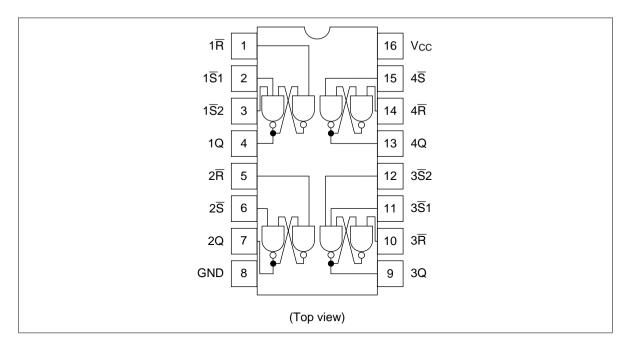
Notes: 1. It is unpredictable, if  $\overline{S}$  or  $\overline{R}$  goes High.

- 2. As to latches which has two  $\overline{S}$  inputs.
  - H: Both of  $\overline{S}$  inputs are high.
  - L: Either or both of  $\overline{S}$  inputs are low.

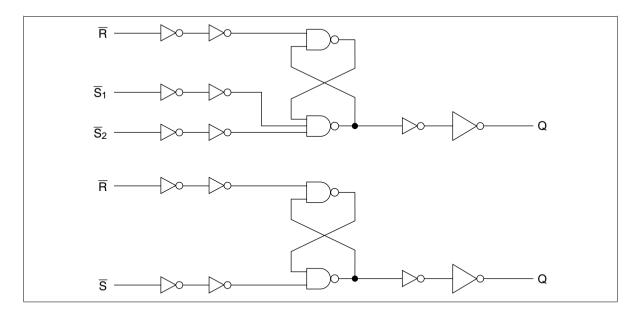


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## **Pin Arrangement**



# Logic Diagram (1/2)



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# **DC Characteristics**

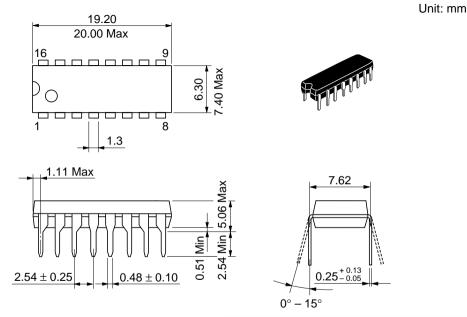
			Ta =	: 25°C	;	Ta = ∙ +85°C	-40 to C			
ltem	Symbol	V <sub>cc</sub> (V)	Min	Тур	Мах	Min	Max	Unit	Test Condition	ns
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	1.5	—	V		
		4.5	3.15			3.15	—	_		
		6.0	4.2	_	_	4.2	_	_		
	V <sub>IL</sub>	2.0	_	_	0.5		0.5	V		
		4.5	_	_	1.35	_	1.35	_		
		6.0	_	_	1.8	—	1.8	-		
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	_	1.9	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -20 μA
		4.5	4.4	4.5		4.4	_	_		
		6.0	5.9	6.0	_	5.9	_	-		
		4.5	4.18	_	_	4.13	_	_		I <sub>он</sub> = -4 mА
		6.0	5.68	_	_	5.63	_	_		I <sub>он</sub> = –5.2 mA
	V <sub>OL</sub>	2.0	_	0.0	0.1	—	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	I <sub>oL</sub> = 20 μA
		4.5	_	0.0	0.1	_	0.1	_		
		6.0	_	0.0	0.1	_	0.1	_		
		4.5	_	_	0.26	—	0.33	-		$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	_	0.33	_		I <sub>oL</sub> = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	$Vin = V_{cc} \text{ or } GI$	ND
Quiescent supply current	I <sub>cc</sub>	6.0	—	—	2.0	—	20	μΑ	$Vin = V_{cc} \text{ or } GI$	ND, lout = $0 \mu A$

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# **AC Characteristics** ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

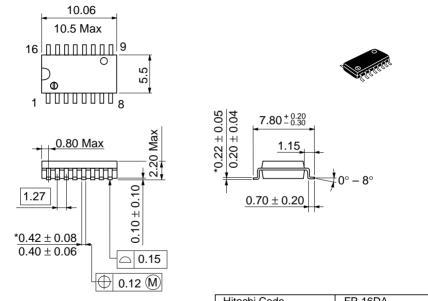
			Ta =	: 25°C	;	Ta = - +85°C			
Item	Symbol	$V_{cc}$ (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t <sub>PLH</sub>	2.0	_	_	130	_	165	ns	$\overline{S}$ to Q
time	t <sub>PHL</sub>	4.5	—	10	26	_	33		
		6.0	_	_	22	—	28	_	
	t <sub>PHL</sub>	2.0	_	—	120	—	150	ns	R to Q
		4.5		12	24	—	30	_	
		6.0			20	—	26	_	
Output rise/fall	t <sub>TLH</sub>	2.0			75	—	95	ns	
time	$t_{\text{THL}}$	4.5		5	15	—	19	_	
		6.0	_	—	13	—	16	-	
Input capacitance	Cin		_	5	10	—	10	pF	

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Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g

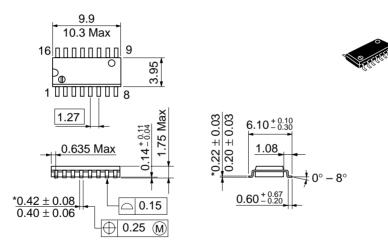
Unit: mm



\*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-16DA
JEDEC	_
EIAJ	Conforms
Weight (reference value)	0.24 g

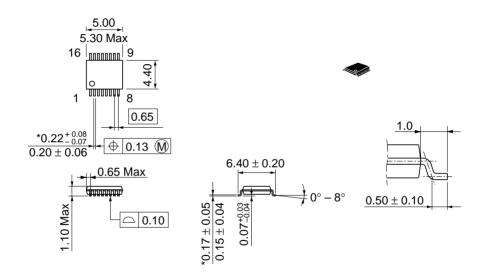
Unit: mm



\*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

Unit: mm



\*Dimension including the plating thickness Base material dimension

Hitachi Code	TTP-16DA
JEDEC	
EIAJ	
Weight (reference value)	0.05 g

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